





Texas **INSTRUMENTS**

SN54HC367, SN74HC367 SCLS309E - JANUARY 1996 - REVISED MARCH 2022

SNx4HC367 Hex Buffers and Line Drivers with 3-State Outputs

1 Features

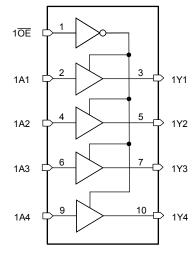
- Wide operating voltage range of 2 V to 6 V
- High-current 3-state outputs drive bus lines, buffer memory address registers, or drive up to 15 LSTTL loads
- True outputs
- Low power consumption, 80- μ A max I_{CC} •
- Typical t_{pd} = 10 ns
- ±6-mA output drive at 5 V ٠
- Low input current of 1µA max •

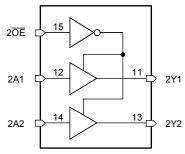
2 Description

The SNx4HC367 is a hex buffer with 3-state outputs. The device is configured into two banks, one with four drivers and one with two drivers, each controlled by its own output enable pin.

Device Information										
PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)								
SN54HC367J	CDIP (16)	24.38 mm × 6.92 mm								
SN74HC367D	SOIC (16)	9.90 mm × 3.90 mm								
SN74HC367N	PDIP (16)	19.31 mm × 6.35 mm								
SN74HC367NS	SO (16)	6.20 mm × 5.30 mm								
SN74HC367PW	TSSOP (16)	5.00 mm × 4.40 mm								

(1) For all available packages, see the orderable addendum at the end of the data sheet.





Functional Block Diagram





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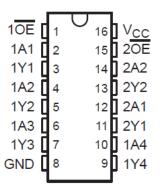
3 Revision History

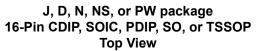
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	Changes from Revision D (September 2003) to Revision E (March 2022) Pa								
•	Updated the numbering, formatting, tables, figures, and cross-references throughout the doucment to re	flect							
	modern data sheet standards	1							



4 Pin Configuration and Functions







5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
I _{IK}	Input clamp current ⁽²⁾	$(V_1 < 0 \text{ or } V_1 > V_{CC})$		±20	mA
I _{ок}	Output clamp current ⁽²⁾	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
I _O	Continuous output current	$(V_{O} = 0 \text{ to } V_{CC})$		±35	mA
	Continuous current through V _C	C or GND		±70	mA
TJ	Junction temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 Recommended Operating Conditions⁽¹⁾

			SN	154HC367		SN	74HC367		UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC}	Supply voltage		2	5	6	2	5	6	V
		V _{CC} = 2 V	1.5			1.5			
VIH	High-level input voltage	V _{CC} = 4.5 V	3.15			3.15			V
		V _{CC} = 6 V	4.2			4.2			
	Low-level input voltage	V _{CC} = 2 V			0.5			0.5	
VIL		V _{CC} = 4.5 V			1.35			1.35	V
		V _{CC} = 6 V			1.8			1.8	
VI	Input voltage		0		V _{CC}	0		V_{CC}	V
Vo	Output voltage		0		V _{CC}	0		V _{CC}	V
		V _{CC} = 2 V			1000			1000	
tt	Input transition rise/fall time	V _{CC} = 4.5 V						500	ns
		V _{CC} = 6 V			400			400	1
T _A	Operating free-air temperature	I	-55		125	-40		85	°C

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report Implications of Slow or Floating SMOS Inputs, literature number SCBA004.

5.3 Thermal Information

		D (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	
THER	MAL METRIC	16 PINS	16 PINS	16 PINS	16 PINS	UNIT
$R_{\theta J A}$	Junction-to-ambient thermal resistance ⁽¹⁾	73	67	64	108	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC package thermal metrics* application report.



5.4 Electrical Characteristics

PARAMETER	TEST	V AA	т	_A = 25°C		SN54HC	367	SN74HC	367	UNIT
PARAMETER	CONDITIONS ⁽¹⁾	V _{cc} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		2	1.9	1.998		1.9		1.9		
	I _{OH} = −20 μA	4.5	4.4	4.499		4.4		4.4		
V _{OH}		6	5.9	5.999		5.9		5.9		V
	I _{OH} = −4 mA	4.5	3.98	4.3		3.7		3.84		
	I _{OH} = −5.2 mA	6	5.48	5.8		5.2		5.34		
	I _{OL} = 20 μA	2		0.002	0.1		0.1		0.1	
		4.5		0.001	0.1		0.1		0.1	
V _{OL}		6		0.001	0.1		0.1		0.1	V
	I _{OL} = 4 mA	4.5		0.17	0.26		0.4		0.33	
	I _{OL} = 5.2 mA	6		0.15	0.26		0.4		0.33	
I _I	$V_{I} = V_{CC} \text{ or } 0$	6		±0.1	±100		±1000		±1000	nA
I _{OZ}	$V_{O} = V_{CC} \text{ or } 0$	6		±0.01	±0.5		±10		±5	μA
I _{CC}	$V_{I} = V_{CC} \text{ or } 0, I_{O}$ $= 0$	6			8		160		80	μA
Ci		2 to 6		3	10		10		10	pF

over recommended operating free-air temperature range (unless otherwise noted)

(1) $V_I = V_{IH}$ or V_{IL} , unless otherwise noted.

5.5 Switching Characteristics

over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (See Figure 6)

	· · ·		U .	-	· · ·																
	PARAMETER	FROM	TO (OUTPUT)	$T_A = 25^{\circ}C$ SN		SN54H	C367	SN74HC	367												
		(INPUT)	10 (001101)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX										
				2		50	95		145		120										
t _{pd}	Propagation delay	A	Y	4.5		12	19		29		24	ns									
				6		10	16		25		20										
				2		100	190		285		238										
t _{en}	Enable time	ŌĒ	Y	4.5		26	38		57		48	ns									
				6		21	32		48		41										
			Y	2		50	175		265		240										
t _{dis}	Diable time	ŌĒ		4.5		21	35		53		48	ns									
			OE	UL I	UE	UE			UE				6		19	30		45		41	
				2		28	60		90		75										
tt	Transition time		Any	4.5		8	12		18		15	ns									
				6		6	10		15		13										



5.5 Switching Characteristics

over recommended operating free-air temperature range, C_L = 150 pF (unless otherwise noted) (See Figure 6)

	PARAMETER	FROM	TO (OUTPUT)	Vcc	T _A = 2	25°C		SN54HC3	67	SN74HC	367		
	FARAMETER	(INPUT)	10 (001701)	(V)	MIN T	ΥP	MAX	MIN N	IAX	MIN	MAX		
	Propagation delay			2		70	120		180		150		
t _{pd}		A	Y	4.5		17	24		36		30	ns	
				6		14	20		31		25		
	Enable time	ŌĒ	Y	Y	2		140	230		345		285	
t _{en}					4.5		30	46		69		57	ns
								6		28	39		59
			Any	2		45	210		315		265		
tt	Transition time			4.5		17	42		63		53	ns	
				6		13	36		53		45		

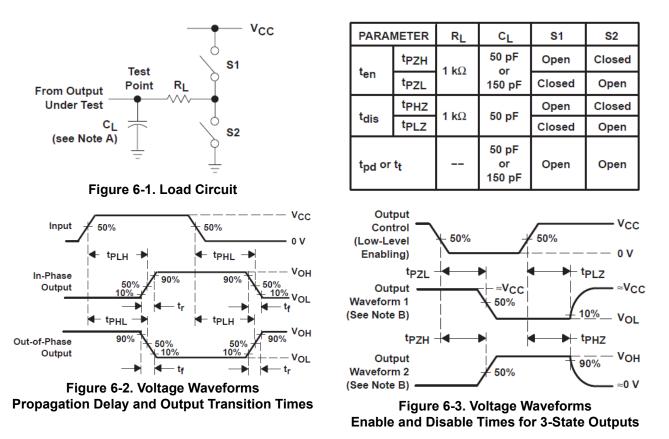
5.6 Operating Characteristics

T_A = 25°C

		Test Conditions	ТҮР	UNIT
C _{pd}	Power dissipation capacitance per buffer/driver	No load	35	pF



6 Parameter Measurement Information



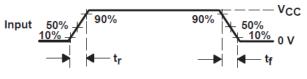


Figure 6-4. Voltage Waveforms Input Rise and Fall Times

A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when diabled by the output control.

Waveform 2 is for an output with internal conditions such that the output is high except when diabled by the output control.

C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following charactersitics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r = 6 ns, t_f = 6 ns.

D. The outputs are measured one at a time with one input transition per measurement.

E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .

- F. t_{PZL} and t_{PZH} are the same as $t_{\text{en}}.$
- G. t_{pd} is the maximum between t_{PLH} and t_{PHL} .
- H. t_t is the maximum between t_{TLH} and t_{THL} .

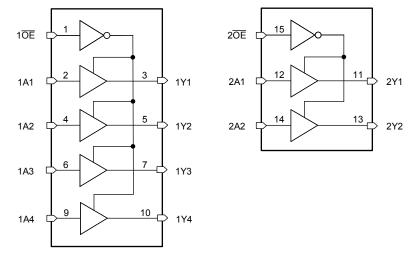


7 Detailed Description

7.1 Overview

These hex buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The 'HC367 devices are organized as dual 4-line and 2-line buffers/drivers with active-low output-enable ($1\overline{OE}$ and $2\overline{OE}$) inputs. When \overline{OE} is low, the device passes noninverted data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

7.2 Functional Block Diagram



Pin numbers hown are for the D, J, N, NS, PW, and W packages.



7.3 Device Functional Modes

(each	(each buffer/driver)										
INP	INPUTS										
ŌĒ	Α	Y									
Н	Х	Z									
L	Н	Н									
L	L	L									

Table 7-1. Function Table (each buffer/driver)



8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

9 Layout

9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.



10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Documentation Support

10.1.1 Related Documentation

10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
8500201EA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8500201EA SNJ54HC367J	Samples
JM38510/65708BEA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65708BEA	Samples
M38510/65708BEA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65708BEA	Samples
SN54HC367J	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SN54HC367J	Samples
SN74HC367DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HC367	Samples
SN74HC367N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC367N	Samples
SN74HC367NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC367	Samples
SN74HC367PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HC367	Samples
SNJ54HC367J	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8500201EA SNJ54HC367J	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



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PACKAGE OPTION ADDENDUM

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54HC367, SN74HC367 :

- Catalog : SN74HC367
- Military : SN54HC367

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC367DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC367NSR	SO	NS	16	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74HC367NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74HC367PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC367PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC367PWR	TSSOP	PW	16	2000	330.0	12.4	6.85	5.45	1.6	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

4-Apr-2024



All ulmensions are norminal							r.
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC367DR	SOIC	D	16	2500	356.0	356.0	35.0
SN74HC367NSR	SO	NS	16	2000	356.0	356.0	35.0
SN74HC367NSR	SO	NS	16	2000	356.0	356.0	35.0
SN74HC367PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
SN74HC367PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
SN74HC367PWR	TSSOP	PW	16	2000	366.0	364.0	50.0

TEXAS INSTRUMENTS

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4-Apr-2024

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74HC367N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC367N	N	PDIP	16	25	506	13.97	11230	4.32

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



NS0016A



PACKAGE OUTLINE

SOP - 2.00 mm max height

SOP



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- Per ASME Y14.5M.
 This drawing is subject to change without notice.
 This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



NS0016A

EXAMPLE BOARD LAYOUT

SOP - 2.00 mm max height

SOP



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



NS0016A

EXAMPLE STENCIL DESIGN

SOP - 2.00 mm max height

SOP



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



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